

Nanoscale physics

Influence of cooling and heating rate on low temperature thermal conductivity of g-Ge₂S₃

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The Thorpe model [1] predict increasing of nanoclusters connectivity in structural matrices of chalcogenide glasses starting at mean coordination number $z=2.4$ (As₂S₃). The compositional (z) changes are influenced on thermal properties of chalcogenide glasses [2]. In [2] the low temperature thermal conductivity of g-As₂S₃ in temperature range from 100 K to 2.5 K measured with cooling rate of 0.385 K/min and heating with rate of 0.415 K/min in the opposite direction was presented. This experiment revealed a hysteresis of $K(T)$ above plateau located in the region of "boson peak". The highest connectivity in Ge-S glassy system is at $z=2.8$ which corresponds to g-Ge₂S₃. For this glass composition during cooling and heating with rate of $v_1 = 0.5$ K/min in similar temperature range as for g-As₂S₃ the hysteresis $k(T)$ was also detected. $\Delta k(T)$ reproduce the density of state in a $g(\omega)/\omega^2$ representation estimated from a Boson peak (BP) experimentally obtained by Raman measurements at room temperature. $\Delta k(T)$ in g-Ge₂S₃ is shifted in high energy side in comparison with $\Delta k(T)$ of g-As₂S₃. It correlates with the "blue" shifting of boson maximum (ν_B) in g-Ge₂S₃, $\nu_B=32$ cm⁻¹ in comparison with its position in g-As₂S₃, $\nu_B = 26$ cm⁻¹. During cooling and heating of g-Ge₂S₃ with rate of $v_2 = 0.2$ K/min the difference of $\Delta k(T)$ is small and hysteresis appears weaker. The region of "plateau" in g-Ge₂S₃ is significantly wider and covered the temperature range from 10 to 40 K in comparison with the region of "plateau" in g-As₂S₃ (3.6 K and 10.7 K). The increases in $k(T)$ values in g-Ge₂S₃ in comparison with those found in g-As₂S₃ correlates well with the increasing of sound velocity in g-Ge₂S₃ relating g-As₂S₃. Role ring correlations in random networks is discussed.

1. M. F. Thorpe and Y. Cai. Mechanical and Vibrational Properties of Network Structures // J. Non-Cryst. Sol. - 1989. - **114**. P.19–24.
2. V. Mitsa, A. Feher, S. Petretskiy, R. Holomb, V. Tkac, P. Ihnatolia and A. Laver. Hysteresis of low-temperature thermal conductivity and Boson peak in glassy (g) As₂S₃: nanocluster contribution // Nanoscale Research Letters - 2017 - 12:345. DOI: 10.1186/s11671-017-2125-6.